

**AMENDMENT**

Serial Number: 10/043065

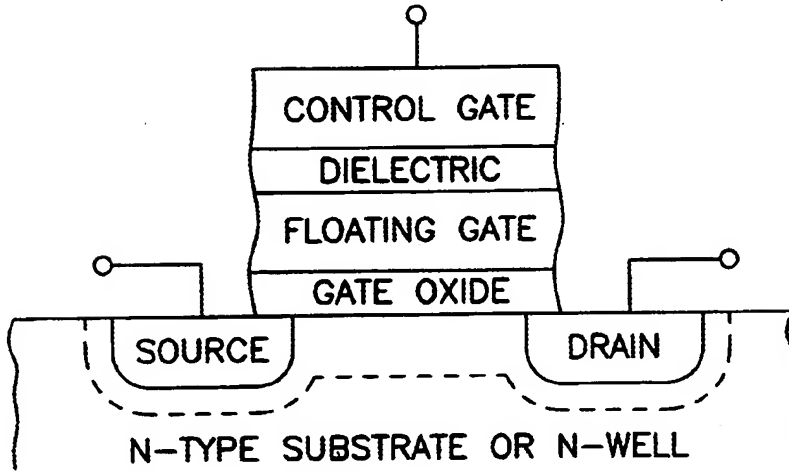
Filing Date: January 9, 2002

Title: P-CHANNEL DYNAMIC FLASH MEMORY CELLS WITH ULTRATHIN TUNNEL OXIDES

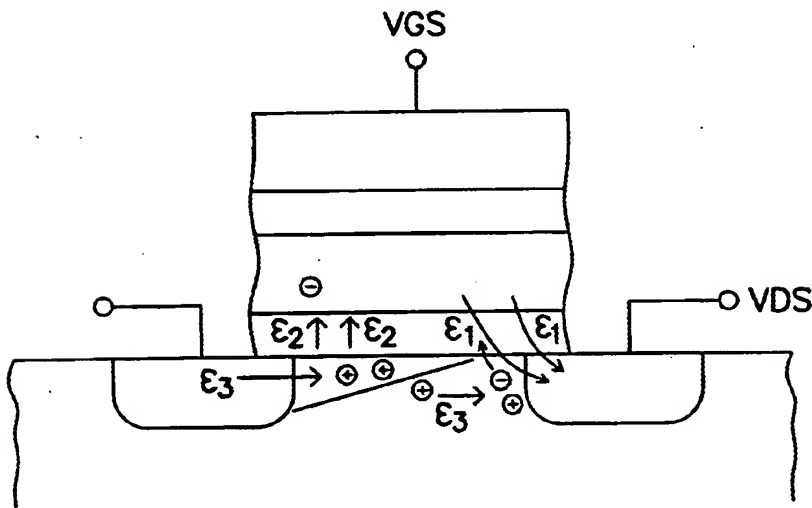
Page 2  
Dkt: 303.684US3

**IN THE DRAWINGS**

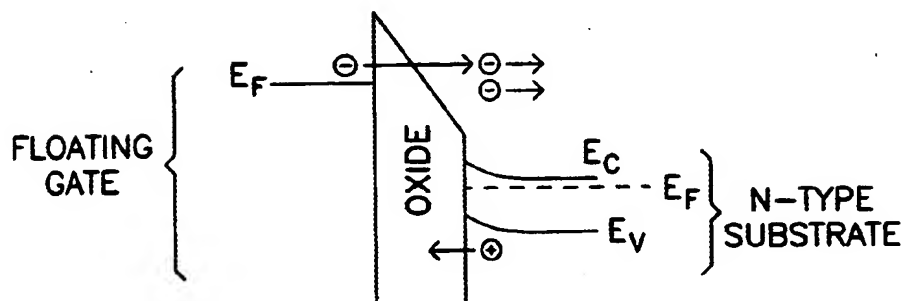
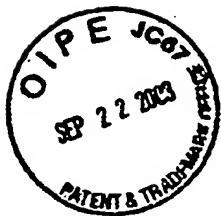
Figure 5B is amended to remove an equation. Applicant has amended the specification to add the deleted equation. A complete set of Formal Drawings is enclosed herewith.



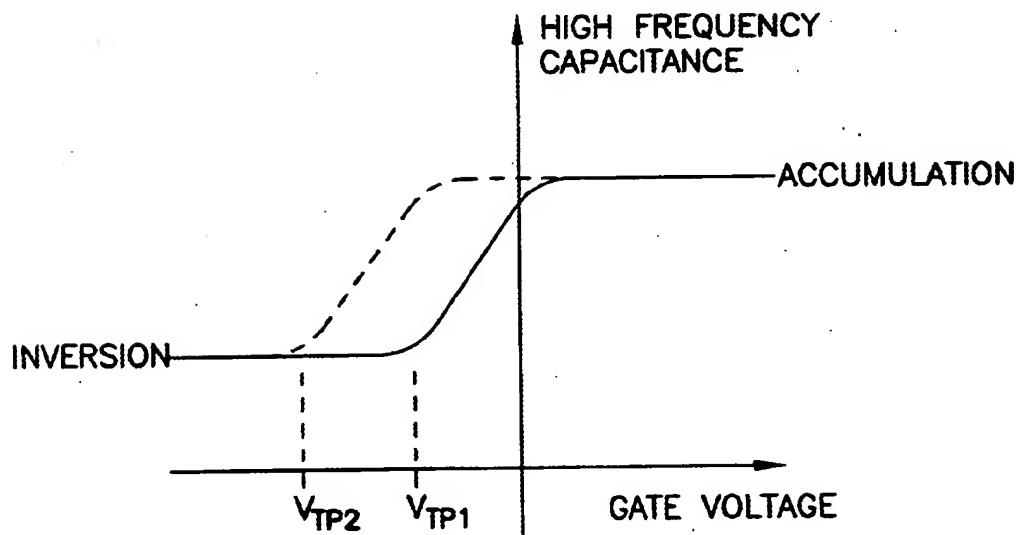
**FIG. 1A**  
(PRIOR ART)  
PMOS



**FIG. 1B**  
(PRIOR ART)



**FIG. 2A**  
(PRIOR ART)



**FIG. 2B**  
(PRIOR ART)



TITLE: P-CHAN

YNAMIC FLASH MEMORY CELLS WITH ULTRATHIN TUNN OXIDES

INVENTORS NAME: Leonard Forbes

DOCKET NO.: 303.684US3

3/10

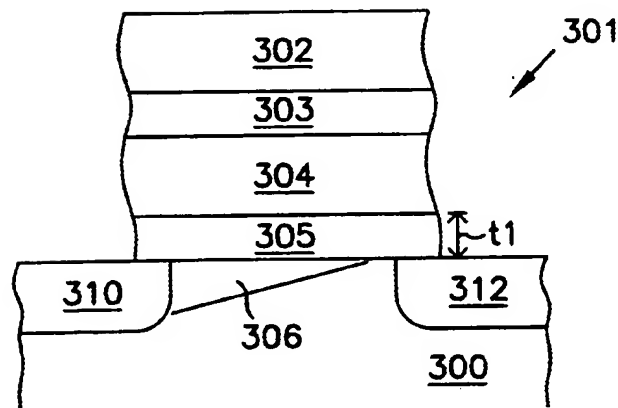


FIG. 3A

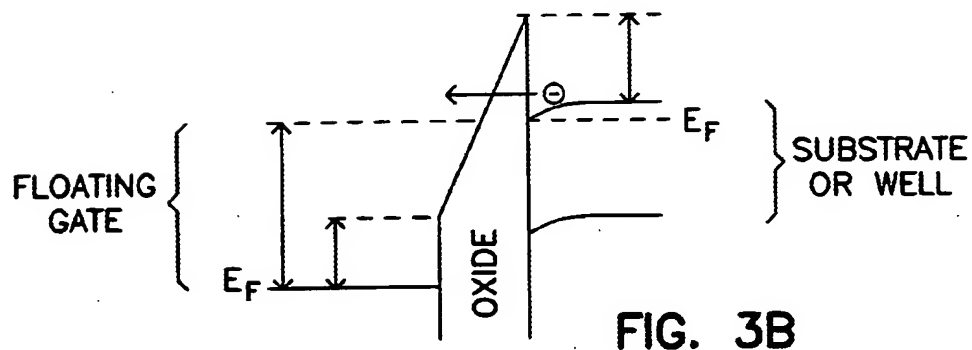


FIG. 3B

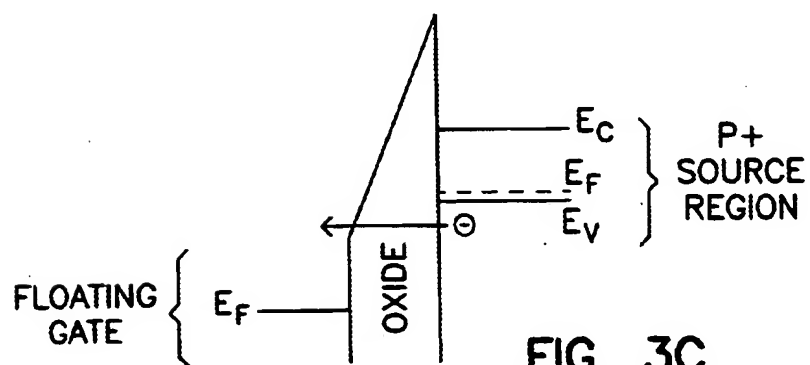


FIG. 3C

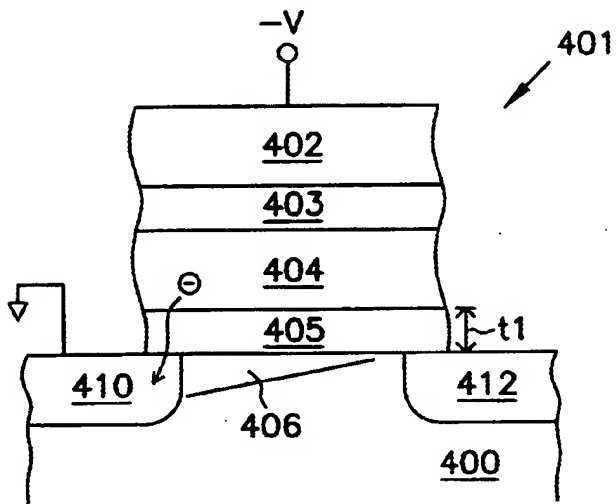


FIG. 4A

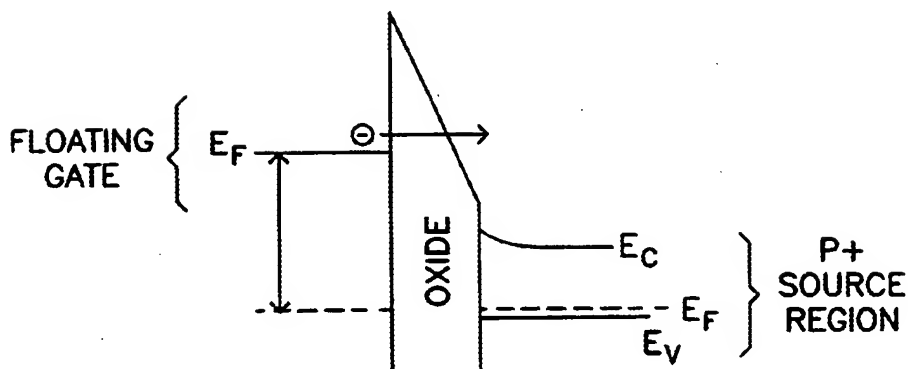


FIG. 4B

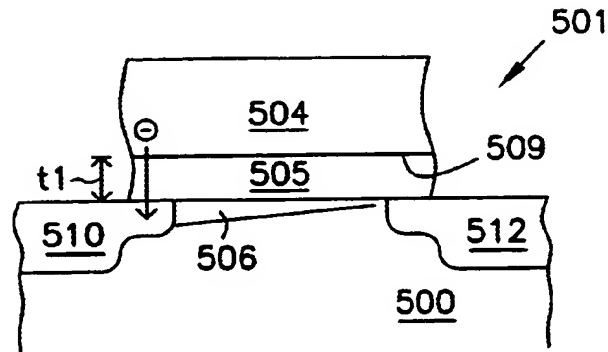
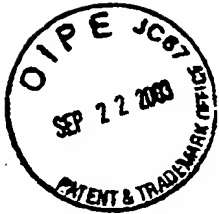


FIG. 5A

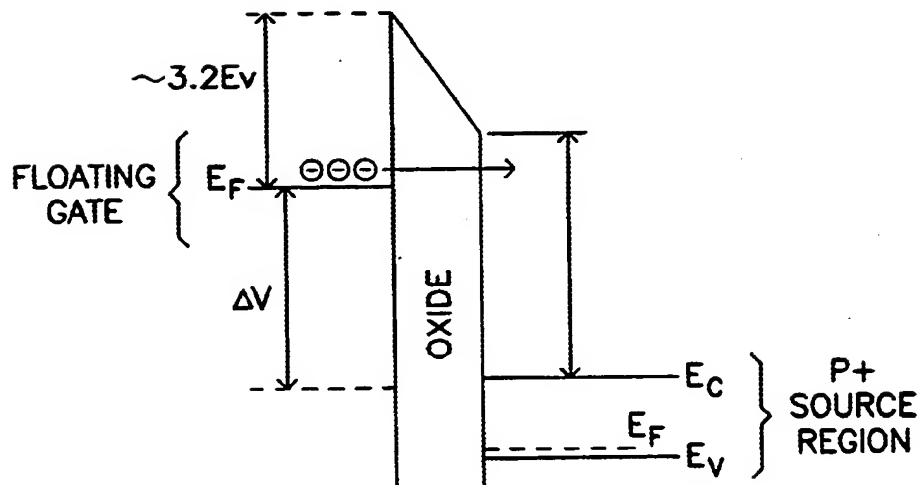


FIG. 5B

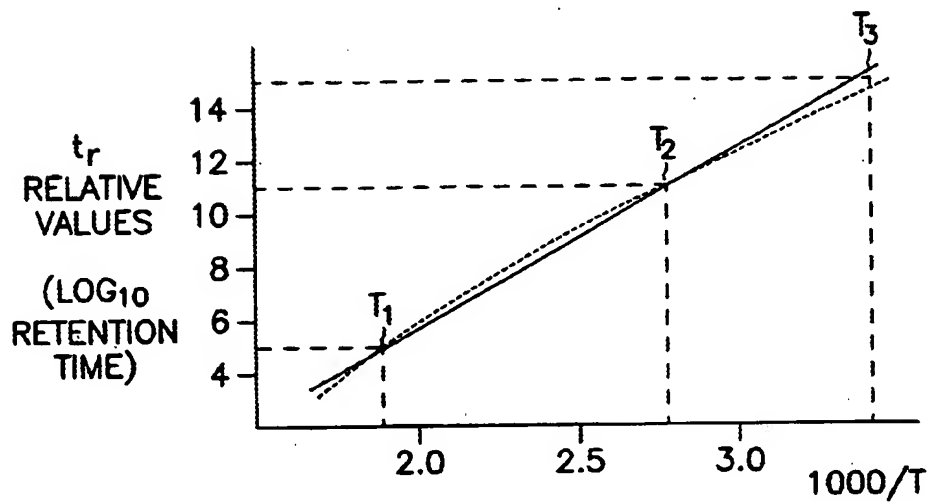
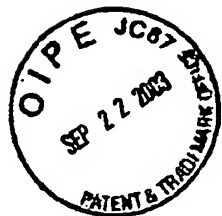


FIG. 6A

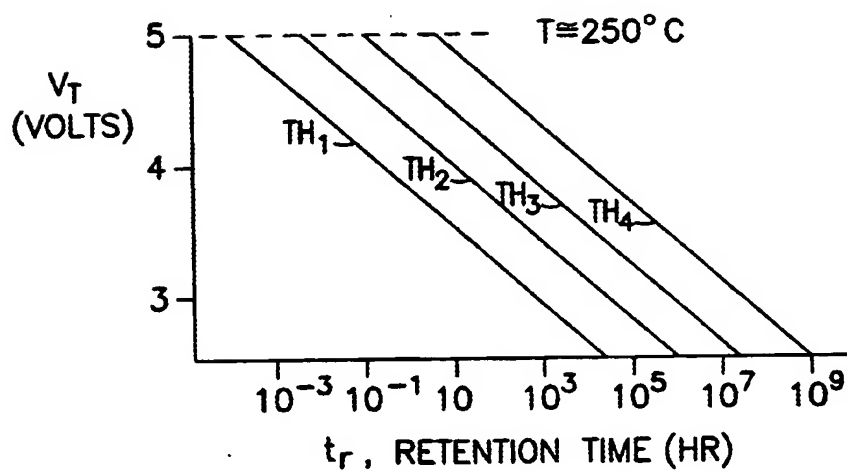


FIG. 6B



TITLE: P-CHAN

YNAMIC FLASH MEMORY CELLS WITH ULTRATHIN TUN

XIDES

INVENTORS NAME: Leonard Forbes

DOCKET NO.: 303.684US3

7/10

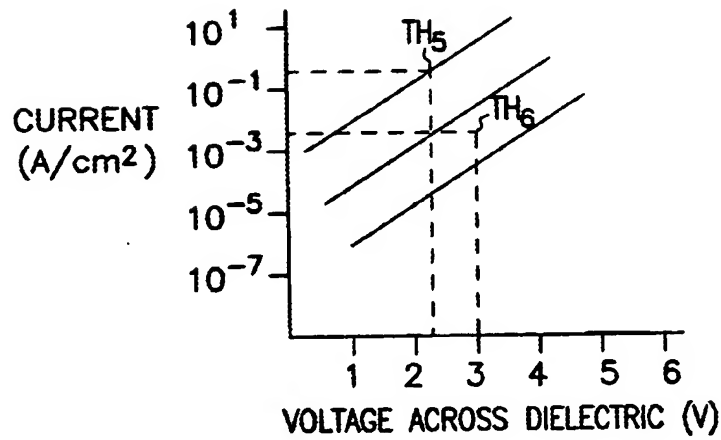


FIG. 7

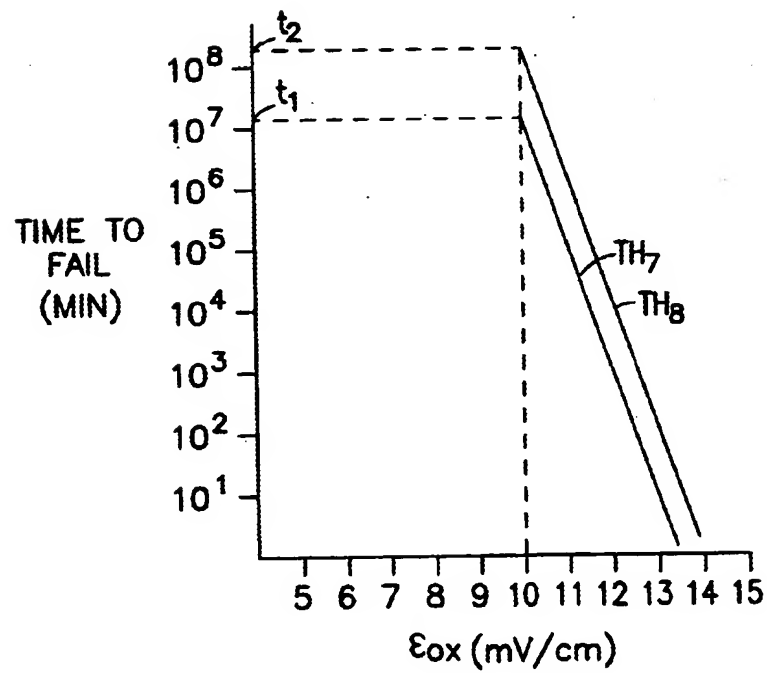
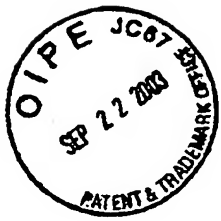


FIG. 8





TITLE: P-CHAN

YNAMIC FLASH MEMORY CELLS WITH ULTRATHIN TUNN XIDES

INVENTORS NAME: Leonard Forbes

DOCKET NO.: 303.684US3

8/10

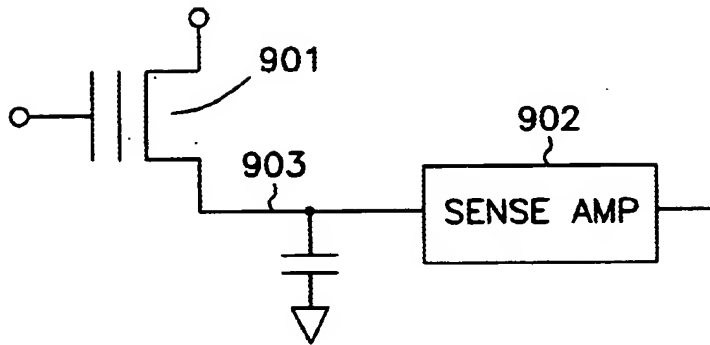


FIG. 9

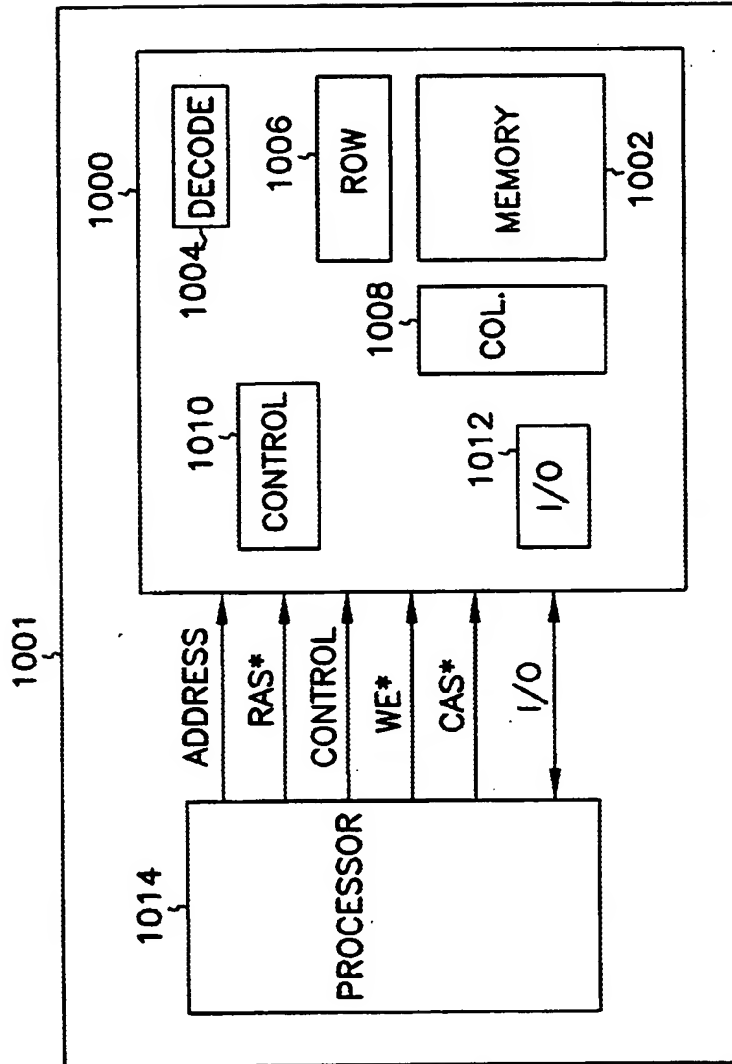


FIG. 10



10/10

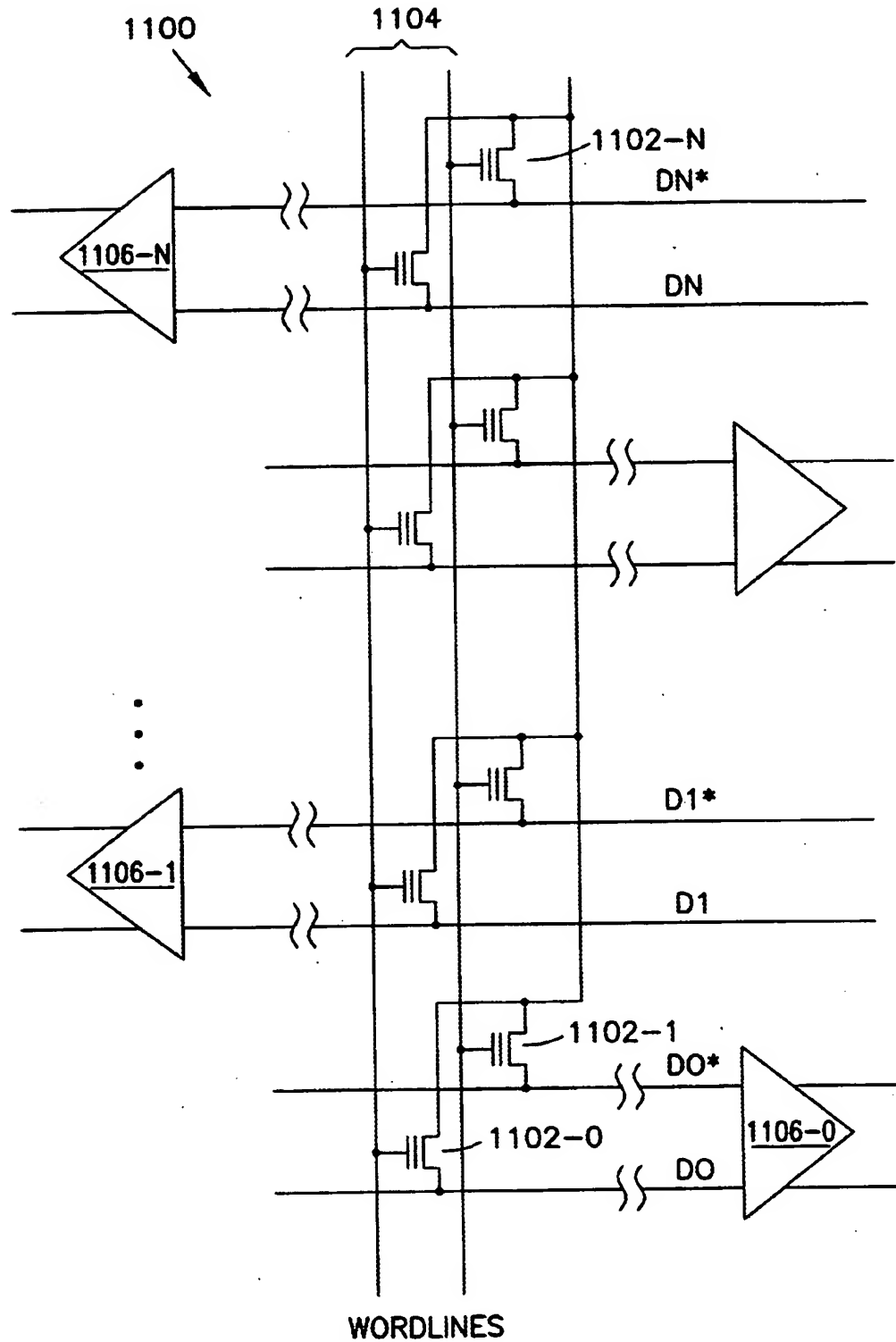


FIG. 11